



# High Voltage Thyristor \ Diode Module

$V_{RRM} = 2 \times 2200 \text{ V}$

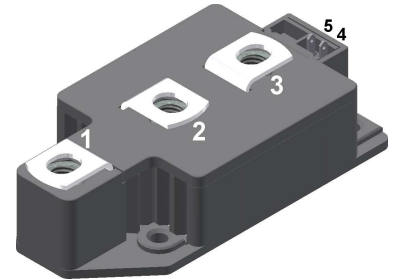
$I_{TAV} = 320 \text{ A}$

$V_T = 1.09 \text{ V}$

Phase leg

Part number

**MCD310-22io1**



Backside: isolated

E72873



### Features / Advantages:

- Thyristor for line frequency
- Planar passivated chip
- Long-term stability
- Direct Copper Bonded Al<sub>2</sub>O<sub>3</sub>-ceramic

### Applications:

- Line rectifying 50/60 Hz
- Softstart AC motor control
- DC Motor control
- Power converter
- AC power control
- Lighting and temperature control

### Package: Y2

- Isolation Voltage: 3600 V~
- Industry standard outline
- RoHS compliant
- Soldering pins for PCB mounting
- Base plate: DCB ceramic
- Reduced weight
- Advanced power cycling

### Disclaimer Notice

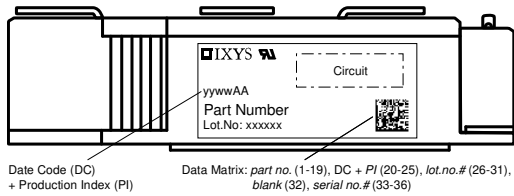
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| Rectifier      |  |   | Ratings                   |      |       |                   |
|----------------|--|---|---------------------------|------|-------|-------------------|
| Symbol         | Definition   | Conditions  | min.                      | typ. | max.  | Unit              |
| $V_{RSM/DSM}$  | max. non-repetitive reverse/forward blocking voltage | $T_{VJ} = 25^{\circ}C$  |                           |      | 2300  | V                 |
| $V_{RRM/DRM}$  | max. repetitive reverse/forward blocking voltage     | $T_{VJ} = 25^{\circ}C$  |                           |      | 2200  | V                 |
| $I_{RD}$       | reverse current, drain current                       | $V_{R/D} = 2200 V$  | $T_{VJ} = 25^{\circ}C$    |      | 1     | mA                |
|                |  | $V_{R/D} = 2200 V$  | $T_{VJ} = 140^{\circ}C$   |      | 40    | mA                |
| $V_T$          | forward voltage drop                                 | $I_T = 300 A$   | $T_{VJ} = 25^{\circ}C$    |      | 1.13  | V                 |
|                |  | $I_T = 600 A$   |                           |      | 1.40  | V                 |
|                |  | $I_T = 300 A$   | $T_{VJ} = 125^{\circ}C$   |      | 1.09  | V                 |
|                |  | $I_T = 600 A$   |                           |      | 1.44  | V                 |
| $I_{TAV}$      | average forward current                              | $T_C = 85^{\circ}C$   | $T_{VJ} = 140^{\circ}C$   |      | 320   | A                 |
| $I_{T(RMS)}$   | RMS forward current                                  | 180° sine   |                           |      | 500   | A                 |
| $V_{T0}$       | threshold voltage                                    | } for power loss calculation only                                   | $T_{VJ} = 140^{\circ}C$   |      | 0.74  | V                 |
| $r_T$          | slope resistance                                     |   |                           |      | 1.16  | mΩ                |
| $R_{thJC}$     | thermal resistance junction to case                  |   |                           |      | 0.11  | K/W               |
| $R_{thCH}$     | thermal resistance case to heatsink                  |   |                           | 0.04 |       | K/W               |
| $P_{tot}$      | total power dissipation                              |   | $T_C = 25^{\circ}C$       |      | 1030  | W                 |
| $I_{TSM}$      | max. forward surge current                           | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$                  | $T_{VJ} = 45^{\circ}C$    |      | 8.00  | kA                |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$                 | $V_R = 0 V$               |      | 8.64  | kA                |
|                |  | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$                  | $T_{VJ} = 140^{\circ}C$   |      | 6.80  | kA                |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$                 | $V_R = 0 V$               |      | 7.35  | kA                |
| $I^2t$         | value for fusing                                     | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$                  | $T_{VJ} = 45^{\circ}C$    |      | 320.0 | kA <sup>2</sup> s |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$                 | $V_R = 0 V$               |      | 310.5 | kA <sup>2</sup> s |
|                |  | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{ sine}$                  | $T_{VJ} = 140^{\circ}C$   |      | 231.2 | kA <sup>2</sup> s |
|                |  | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{ sine}$                 | $V_R = 0 V$               |      | 224.4 | kA <sup>2</sup> s |
| $C_J$          | junction capacitance                                 | $V_R = 700 V \quad f = 1 \text{ MHz}$                               | $T_{VJ} = 25^{\circ}C$    |      | 235   | pF                |
| $P_{GM}$       | max. gate power dissipation                          | $t_p = 30 \mu s$  | $T_C = 140^{\circ}C$      |      | 120   | W                 |
|                |  | $t_p = 500 \mu s$   |                           |      | 60    | W                 |
| $P_{GAV}$      | average gate power dissipation                       |   |                           |      | 20    | W                 |
| $(di/dt)_{cr}$ | critical rate of rise of current                     | $T_{VJ} = 140^{\circ}C; f = 50 \text{ Hz}$                          | repetitive, $I_T = 960 A$ |      | 100   | A/μs              |
|                |  | $t_p = 200 \mu s; di_G/dt = 1 A/\mu s;$                             | non-repet., $I_T = 320 A$ |      | 500   | A/μs              |
| $(dv/dt)_{cr}$ | critical rate of rise of voltage                     | $V = \frac{2}{3} V_{DRM}$   | $T_{VJ} = 140^{\circ}C$   |      | 1000  | V/μs              |
|                |  | $R_{GK} = \infty; \text{method 1 (linear voltage rise)}$            |                           |      |       |                   |
| $V_{GT}$       | gate trigger voltage                                 | $V_D = 6 V$   | $T_{VJ} = 25^{\circ}C$    |      | 2     | V                 |
|                |  |   | $T_{VJ} = -40^{\circ}C$   |      | 3     | V                 |
| $I_{GT}$       | gate trigger current                                 | $V_D = 6 V$   | $T_{VJ} = 25^{\circ}C$    |      | 150   | mA                |
|                |  |   | $T_{VJ} = -40^{\circ}C$   |      | 200   | mA                |
| $V_{GD}$       | gate non-trigger voltage                             | $V_D = \frac{2}{3} V_{DRM}$   | $T_{VJ} = 140^{\circ}C$   |      | 0.25  | V                 |
| $I_{GD}$       | gate non-trigger current                             |   |                           |      | 10    | mA                |
| $I_L$          | latching current                                     | $t_p = 30 \mu s$  | $T_{VJ} = 25^{\circ}C$    |      | 200   | mA                |
|                |  | $I_G = 0.45 A; di_G/dt = 0.45 A/\mu s$                              |                           |      |       |                   |
| $I_H$          | holding current                                      | $V_D = 6 V \quad R_{GK} = \infty$                                   | $T_{VJ} = 25^{\circ}C$    |      | 150   | mA                |
| $t_{gd}$       | gate controlled delay time                           | $V_D = \frac{1}{2} V_{DRM}$   | $T_{VJ} = 25^{\circ}C$    |      | 2     | μs                |
|                |  | $I_G = 1 A; di_G/dt = 1 A/\mu s$                                    |                           |      |       |                   |
| $t_q$          | turn-off time  | $V_R = 100 V; I_T = 320 A; V = \frac{2}{3} V_{DRM}$                 | $T_{VJ} = 125^{\circ}C$   |      | 350   | μs                |
|                |  | $di/dt = 10 A/\mu s \quad dv/dt = 50 V/\mu s \quad t_p = 200 \mu s$ |                           |      |       |                   |



| Package Y2    |  |                      | Ratings |      |      |      |
|---------------|--|----------------------|---------|------|------|------|
| Symbol        | Definition   | Conditions           | min.    | typ. | max. | Unit |
| $I_{RMS}$     | RMS current  | per terminal         |         |      | 600  | A    |
| $T_{VJ}$      | virtual junction temperature                                 |                      | -40     |      | 140  | °C   |
| $T_{op}$      | operation temperature  |                      | -40     |      | 125  | °C   |
| $T_{stg}$     | storage temperature  |                      | -40     |      | 125  | °C   |
| <b>Weight</b> |  |                      |         | 255  |      | g    |
| $M_D$         | mounting torque  |                      | 2.5     |      | 5    | Nm   |
| $M_T$         | terminal torque  |                      | 12      |      | 15   | Nm   |
| $d_{Spp/App}$ | creepage distance on surface   striking distance through air | terminal to terminal | 13.0    |      |      | mm   |
| $d_{Spb/Apb}$ |  | terminal to backside | 13.0    |      |      | mm   |
| $V_{ISOL}$    | isolation voltage  | t = 1 second         | 3600    |      |      | V    |
|               |  | t = 1 minute         | 3000    |      |      | V    |



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | MCD310-22io1    | MCD310-22io1       | Box           | 2        | 470295   |

**Equivalent Circuits for Simulation**

\* on die level

$T_{VJ} = 140^{\circ}\text{C}$

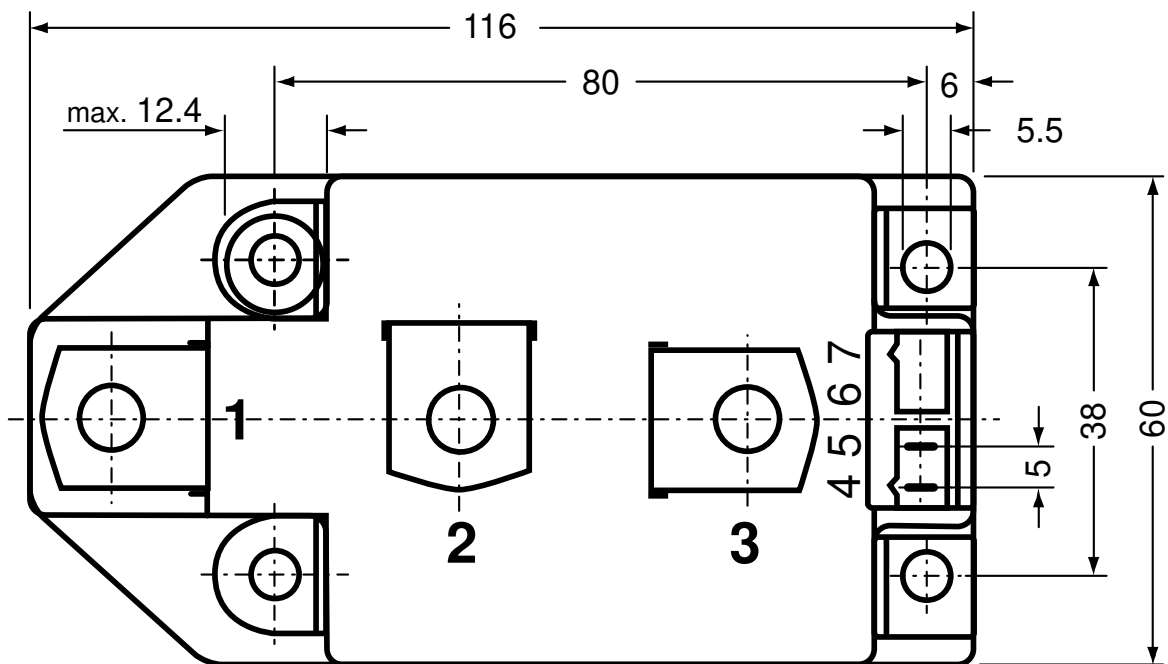
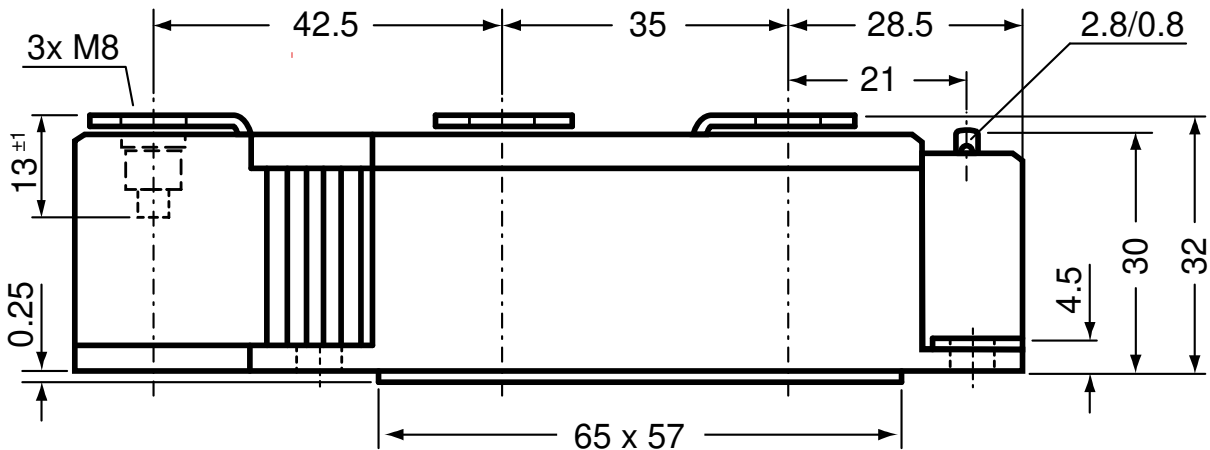


**Thyristor**

|              |                    |      |    |
|--------------|--------------------|------|----|
| $V_{0\ max}$ | threshold voltage  | 0.74 | V  |
| $R_{0\ max}$ | slope resistance * | 0.97 | mΩ |

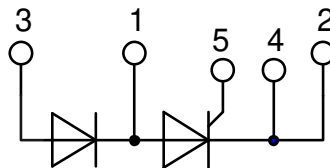


Outlines Y2



Optional accessories for modules

Keyed gate/cathode twin plugs with wire length = 350 mm, gate = white, cathode = red  
Type ZY 180L (L = Left for pin pair 4/5) UL 758, style 3751



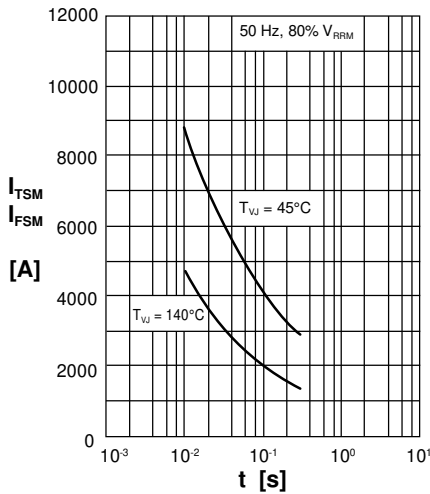
**Thyristor**


Fig. 1 Surge overload current  
 $I_{T(F)SM}$ : crest value, t: duration

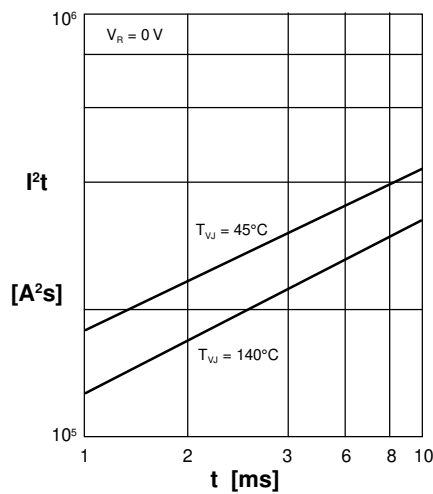


Fig. 2  $I^2t$  versus time (1-10 ms)

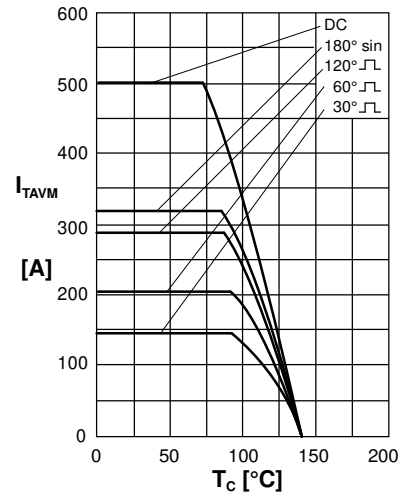


Fig. 3 Max. forward current at case temperature

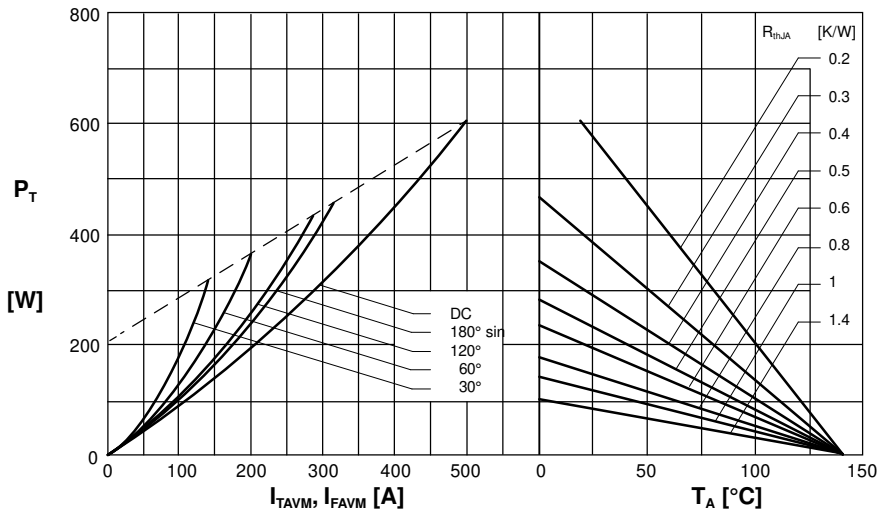


Fig. 4 Power dissipation versus onstate current and ambient temperature (per thyristor/diode)

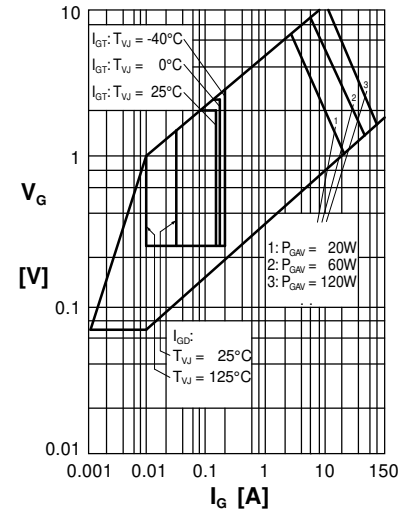


Fig. 5 Gate trigger characteristics

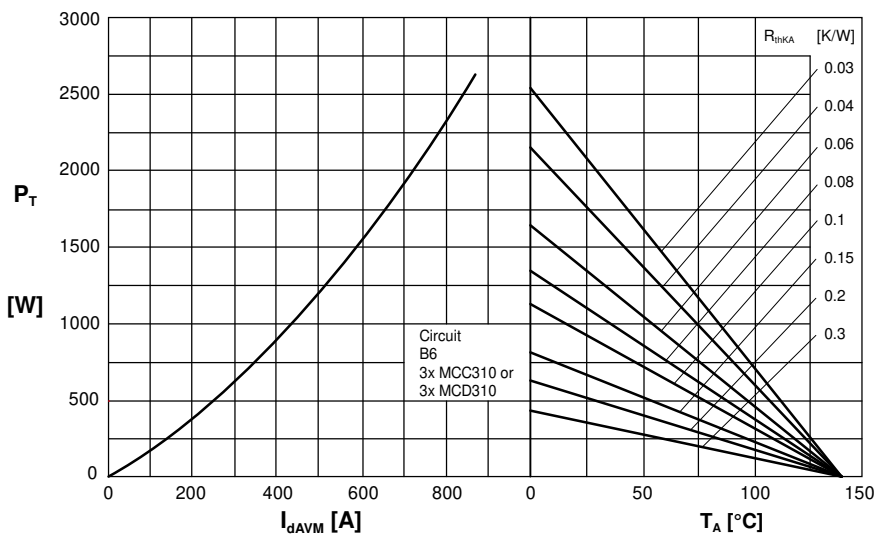


Fig. 6 Three phase rectifier bridge: Power dissipation versus direct output current and ambient temperature

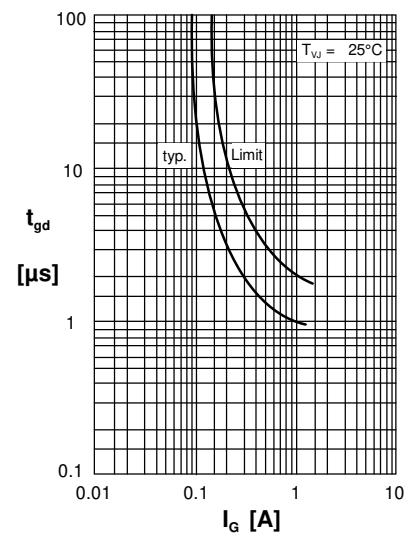


Fig. 7 Gate trigger delay time



**Rectifier**

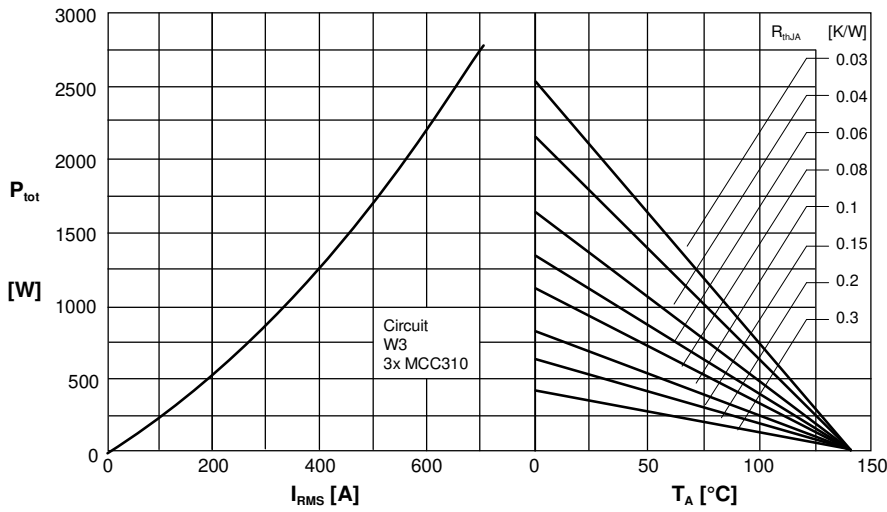


Fig. 7 Three phase AC-controller: • Power dissipation versus RMS output current and ambient temperature

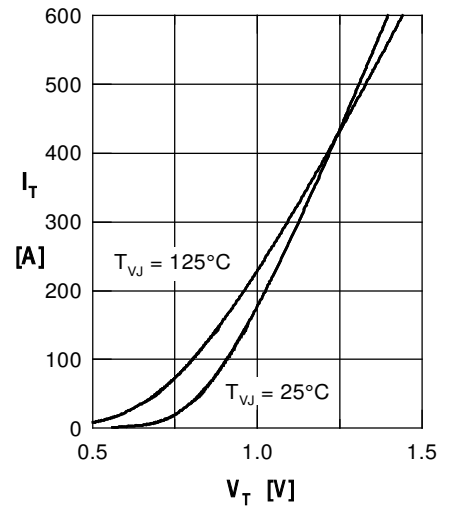


Fig. 10 Forward characteristics

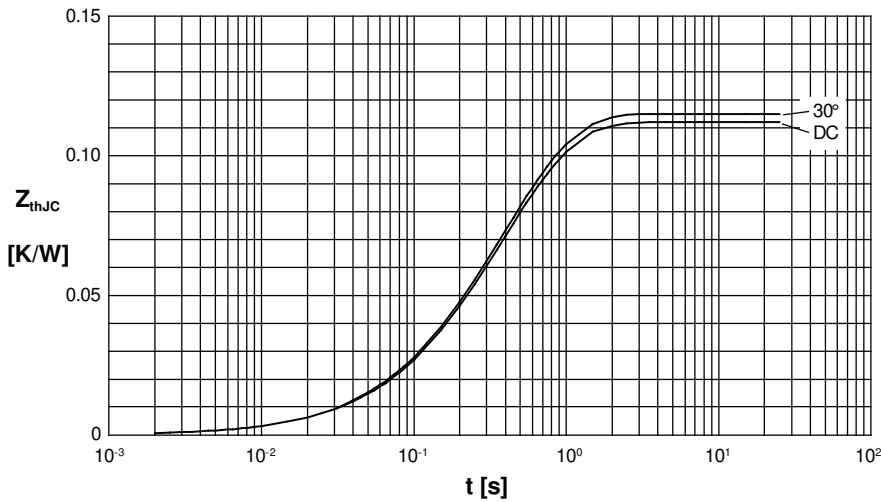


Fig. 8 Transient thermal impedance junction to case (per thyristor)

$R_{\theta JC}$  for various conduction angles  $d$ :

| $d$   | $R_{\theta JC}$ (K/W) |
|-------|-----------------------|
| DC    | 0.112                 |
| 180°C | 0.113                 |
| 120°C | 0.114                 |
| 60°C  | 0.115                 |
| 30°C  | 0.115                 |

Constants for  $Z_{\theta JC}$  calculation:

| $i$ | $R_{\theta i}$ [K/W] | $t_i$ [s] |
|-----|----------------------|-----------|
| 1   | 0.003                | 0.099     |
| 2   | 0.0143               | 0.168     |
| 3   | 0.0947               | 0.456     |

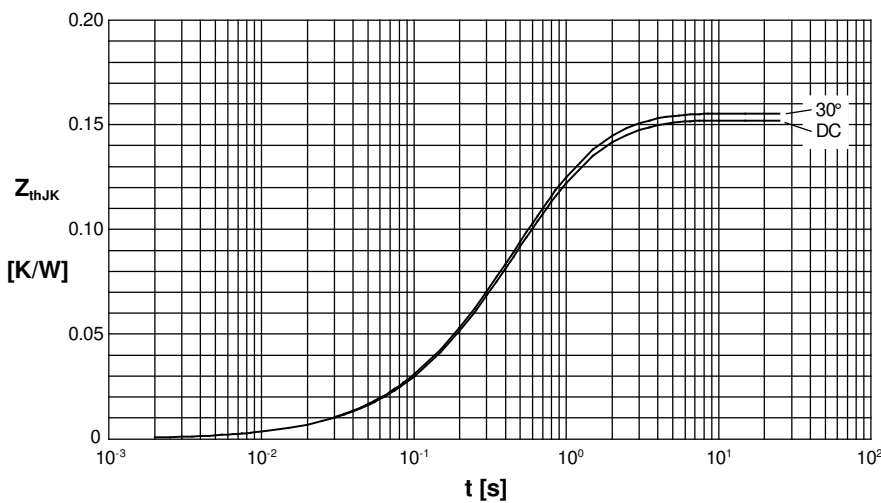


Fig. 9 Transient thermal impedance junction to heatsink (per thyristor)

$R_{\theta JK}$  for various conduction angles  $d$ :

| $d$   | $R_{\theta JK}$ [K/W] |
|-------|-----------------------|
| DC    | 0.152                 |
| 180°C | 0.154                 |
| 120°C | 0.154                 |
| 60°C  | 0.155                 |
| 30°C  | 0.155                 |

Constants for  $Z_{\theta JK}$  calculation:

| $i$ | $R_{\theta i}$ (K/W) | $t_i$ (s) |
|-----|----------------------|-----------|
| 1   | 0.003                | 0.099     |
| 2   | 0.0143               | 0.168     |
| 3   | 0.0947               | 0.456     |
| 4   | 0.04                 | 1.36      |